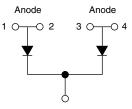
# VS-UFB310CB40



**Vishay Semiconductors** 

# Not Insulated SOT-227 Power Module Ultrafast Rectifier, 310 A





Base common cathode

PRIMARY CHARACTERISTICS							
V <sub>R</sub>	400 V						
$I_{F(AV)}$ at $T_C = 119 \ ^\circ C$ per module $^{(1)}$	310 A						
t <sub>rr</sub>	39 ns						
at T <sub>C</sub>	135 °C						
Туре	Modules - diode, FRED Pt®						
Package	SOT-227						

Note

(1) All 4 anode terminals connected

## **FEATURES**

- Not insulated package
- Ultrafast reverse recovery
- · Ultrasoft reverse recovery current shape
- Optimized for power conversion: welding and industrial SMPS applications
- · Plug-in compatible with other SOT-227 packages
- · Easy to assemble
- · Direct mounting to heatsink
- UL approved file E222165
- · Designed and qualified for industrial level
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

## **DESCRIPTION / APPLICATIONS**

The VS-UFB310CB40 not insulated modules integrate two state of the art ultrafast recovery rectifiers in the compact. industry standard SOT-227 package. The planar structure of the diodes, and the platinum doping life time control, provide a ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics.

These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, DC/DC converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/RFI.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V <sub>R</sub>		400	V
Continuous forward current per diode	IF	T <sub>C</sub> = 135 °C	155	۸
Single pulse forward current per diode	I <sub>FSM</sub> <sup>(1)</sup>	T <sub>C</sub> = 25 °C	1300	A
Maximum power dissipation per module	PD	T <sub>C</sub> = 135 °C	421	W
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C

#### Note

<sup>(1)</sup> 10 ms sine or 6 ms rectangular pulse



COMPLIANT



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ELECTRICAL SPECIFICATIONS PER DIODE ( $T_J = 25 \text{ °C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA	400	-	-	
		I <sub>F</sub> = 100 A	-	1.11	1.34	
		I <sub>F</sub> = 100 A, T <sub>J</sub> = 125 °C	-	0.99	1.1	V
Forward voltage, per leg	V <sub>FM</sub>	I <sub>F</sub> = 100 A, T <sub>J</sub> = 175 °C	-	0.97	-	
		I <sub>F</sub> = 200 A	-	1.3	1.6	
		I <sub>F</sub> = 200 A, T <sub>J</sub> = 125 °C	-	1.22	1.4	
		I <sub>F</sub> = 200 A, T <sub>J</sub> = 175 °C	-	1.25	-	
		$V_{R} = V_{R}$ rated	-	1.3	50	
Reverse leakage current, per leg	I <sub>RM</sub>	$V_R = V_R$ rated, $T_J = 125 \text{ °C}$	-	100	-	μΑ
		$V_R = V_R$ rated, $T_J = 175 \text{ °C}$	-	1	4	mA
Junction capacitance, per leg	CT	V <sub>R</sub> = 400 V	-	100	-	pF

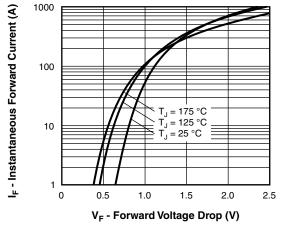
<b>DYNAMIC RECOVERY CHARACTERISTICS PER DIODE</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CC	NDITIONS	MIN.	TYP.	MAX.	UNITS
		I <sub>F</sub> = 1.0 A, dI <sub>F</sub> /dt =	= 400 A/µs, V <sub>R</sub> = 30 V	-	39	-	
Reverse recovery time, per leg	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	89	-	ns
		T <sub>J</sub> = 125 °C		-	184	-	
		T <sub>J</sub> = 25 °C	$I_{\rm F} = 50  {\rm A}$	-	9	-	A
Feak recovery current, per leg	eak recovery current, per leg		dl <sub>F</sub> /dt = 200 A/µs V <sub>R</sub> = 200 V	-	20	-	
Boyeros recovery obergo, per log	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	400	-	nC
Reverse recovery charge, per leg		T <sub>J</sub> = 125 °C		-	1840	-	

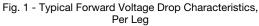
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C
Junction to case, single leg conducting	Р		-	-	0.19	
Junction to case, both leg conducting	R <sub>thJC</sub>		-	-	0.095	°C/W
Case to heatsink	R <sub>thCS</sub>	Flat, greased surface	-	0.07	-	
Weight			-	30	-	g
Mounting torque		Torque to terminal	-	-	1.1 (9.7)	Nm (lbf.in)
Mounting torque		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)
Case style				SOT-227	not insulate	ed

# VS-UFB310CB40

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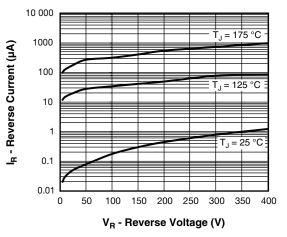
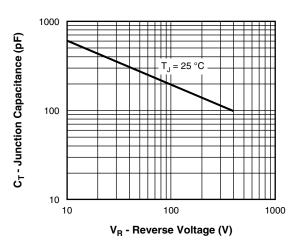
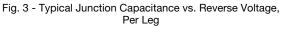


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Leg





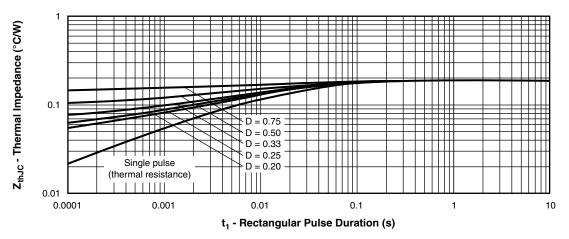


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics, Per Leg

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180

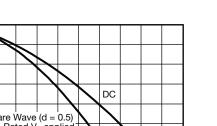
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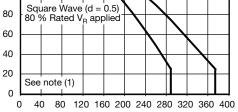
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120

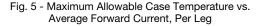
100

Allowable Case Temperature (°C)





I<sub>F(AV)</sub> - Average Forward Current (A)



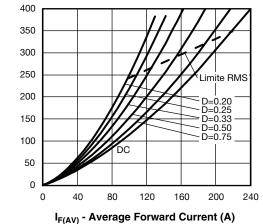


Fig. 6 - Forward Power Loss Characteristics, Per Leg

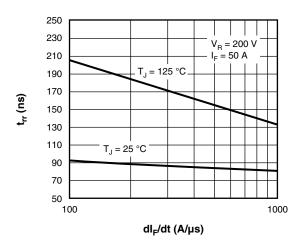


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt, Per Leg

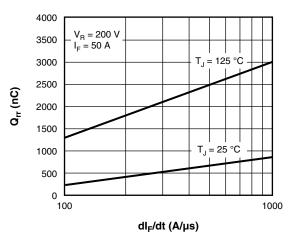


Fig. 8 - Typical Reverse Recovery Charge vs. dl<sub>F</sub>/dt, Per Leg

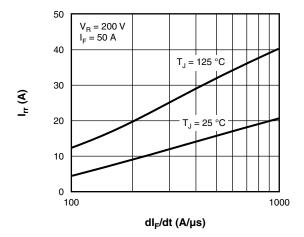


Fig. 9 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt, Per Leg

Average Power Loss (W)

VS-UFB310CB40

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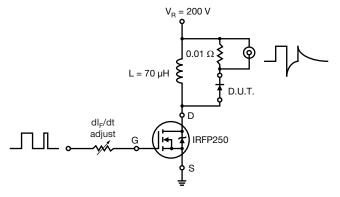


Fig. 10 - Reverse Recovery Parameter Test Circuit

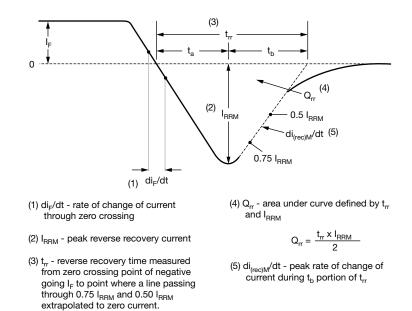


Fig. 11 - Reverse Recovery Waveform and Definitions

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## **ORDERING INFORMATION TABLE**

Device code	vs-	UF	В	310	с	В	40	
	1	2	3	4	5	6	7	
	1 - 2 - 3 - 4 - 5 - 6 -	Ultra Ultra Cur Circ	afast reo afast Pt rent rationalise	diffused ng (310 iguratior	l = 310 A n (two di	() Nodes co		cathode )
	7 -	<ul> <li>Package indicator (SOT-227 standard not insulated</li> <li>Voltage rating (40 = 400 V)</li> </ul>						

Quantity per tube is 10 pcs, M4 screw and washer included

CIRCUIT CONFIGURATION						
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
Two diodes common cathode	С	Lead Assignment				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95423				
Packaging Information	www.vishay.com/doc?95425				

**Vishay Semiconductors** 



SOT-227 Generation 2

#### **DIMENSIONS** in millimeters (inches)



#### Note

• Controlling dimension: millimeter



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